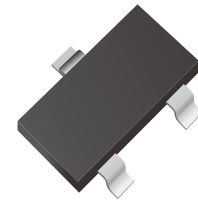
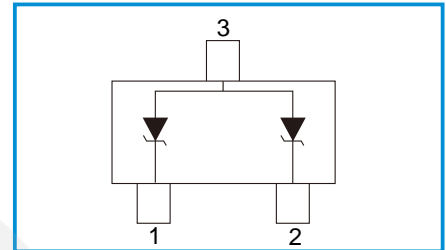


Uni-direction ESD Protection Diode

Features

- Uni-directional ESD protection of one line
- Reverse stand-off voltage: 5V
- Low reverse clamping voltage
- Low leakage current
- Excellent package: 2.90mm × 1.30mm × 1.00mm
- Fast response time
- JESD22-A114-B ESD Rating of class 3B per human body model
- IEC 61000-4-2 Level 4 ESD protection
- Marking: 5M


Functional Diagram


Applications

- Computers and peripherals
- Audio and video equipment
- Cellular handsets and accessories
- Portable electronics
- Other electronics equipments communication systems

Absolute Maximum Ratings (T_{amb}=25°C unless otherwise specified)

Parameter	Symbol	Limit	Unit
IEC 61000-4-2 ESD Voltage	V _{ESD} ⁽¹⁾	Air Model	±25
		Contact Model	±25
		Per Human Body Model	±16
		Machine Model	±0.4
ESD Voltage			kV
Peak Pulse Power	P _{PP} ⁽²⁾	170	W
Peak Pulse Current	I _{PP} ⁽²⁾	13	A
Lead Solder Temperature - Maximum (10 Second Duration)	T _L	260	°C
Junction Temperature	T _j	150	°C
Storage Temperature Range	T _{stg}	-55 ~ +150	°C

(1). Device stressed with ten non-repetitive ESD pulses.

(2). Non-repetitive current pulse 8/20μs exponential decay waveform according to IEC61000-4-5.

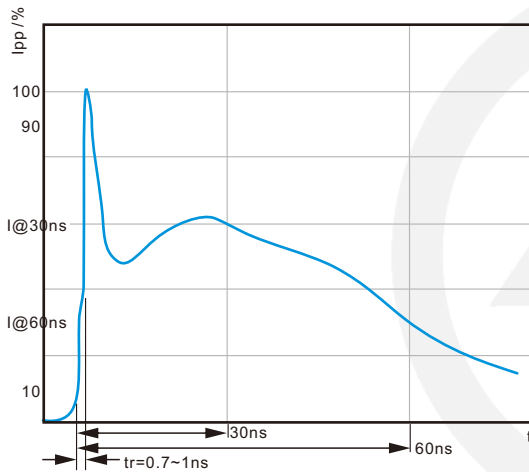
ESD standards compliance

IEC61000-4-2 Standard

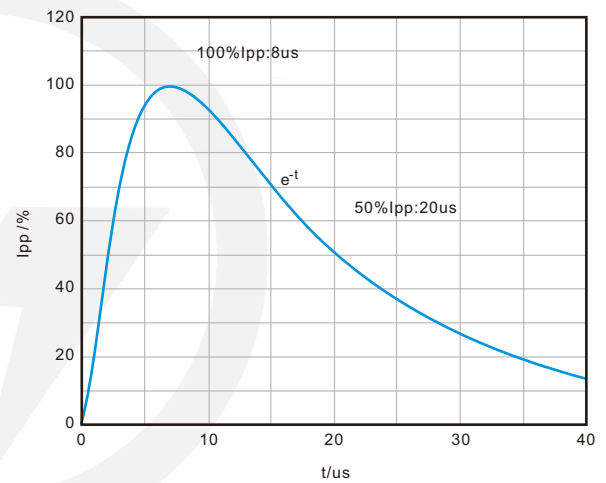
Contact Discharge		Air Discharge	
Level	Test Voltage kV	Level	Test Voltage kV
1	2	1	2
2	4	2	4
3	6	3	8
4	8	4	15

JESD22-A114-B Standard

ESD Class	Human Body Discharge V
0	0~249
1A	250~499
1B	500~999
1C	1000~1999
2	2000~3999
3A	4000~7999
3B	8000~15999



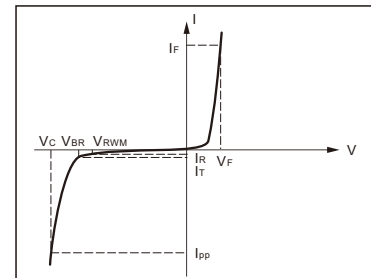
ESD pulse waveform according to IEC61000-4-2



8/20µs pulse waveform according to IEC 61000-4-5

Electrical Parameter

Symbol	Parameter
V_C	Clamping Voltage @ I_{PP}
I_{PP}	Peak Pulse Current
V_{BR}	Breakdown Voltage @ I_T
I_T	Test Current
I_R	Reverse Leakage Current @ V_{RWM}
V_{RWM}	Reverse Standoff Voltage
V_F	Forward Voltage @ I_F
I_F	Forward Current



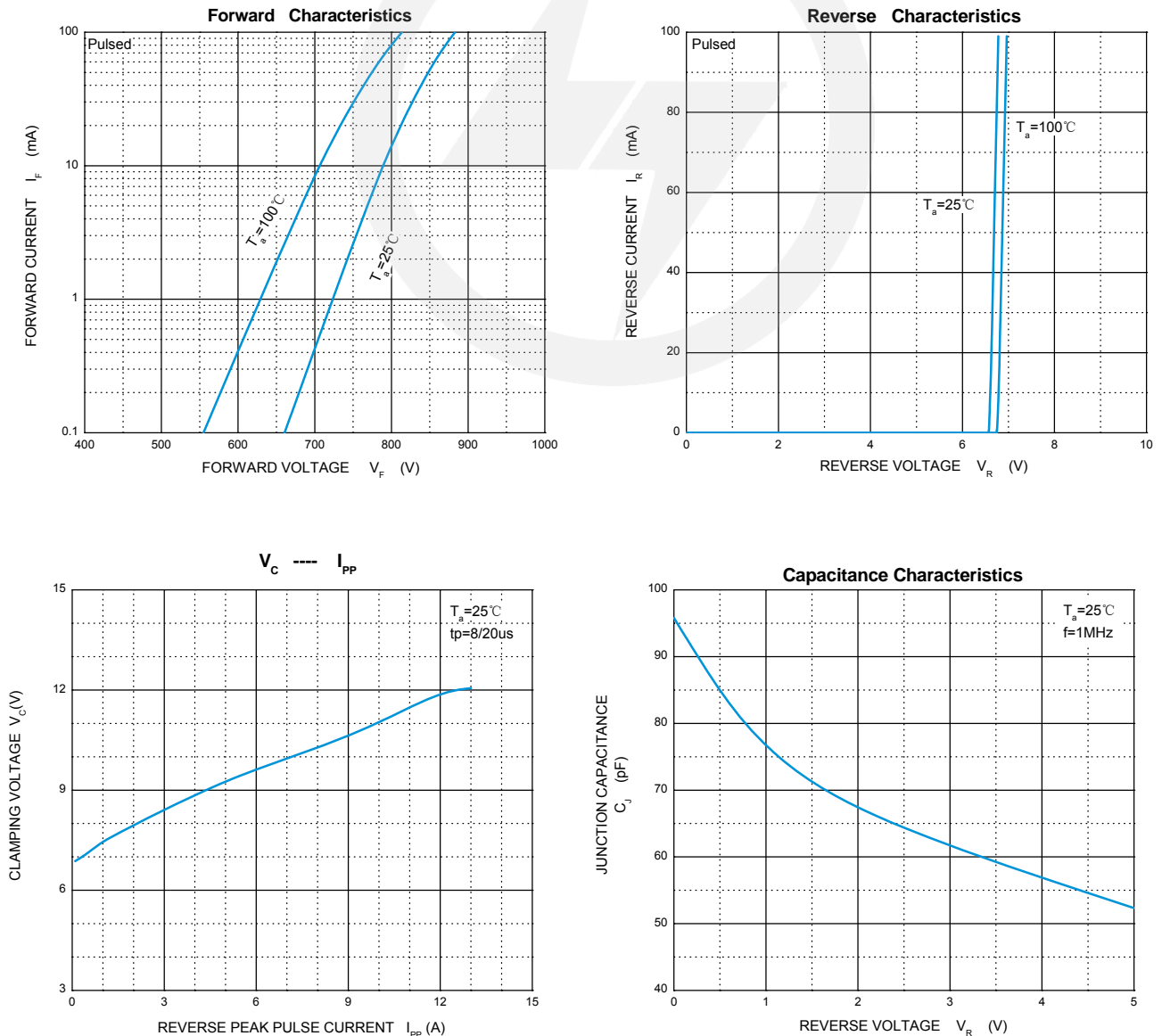
V-I characteristics for a uni-directional TVS

Electrical Characteristics($T_A=25^{\circ}\text{C}$ unless otherwise specified)

Parameter	Symbol	Test conditions	Min	Typ	Max	Unit
Reverse stand off voltage	$V_{RWM}^{(1)}$				5	V
Reverse leakage current	I_R	$V_{RWM}=5\text{V}$			10	μA
Breakdown voltage	$V_{(BR)}$	$I_T=1\text{mA}$	6.2		7.3	V
Clamping voltage	$V_C^{(2)}$	$I_{PP}=13\text{A}$			13	V
Forward voltage	V_F	$I_F=10\text{mA}$			0.9	V
Junction capacitance	C_J	$V_R=0\text{V}, f=1\text{MHz}$		95		pF

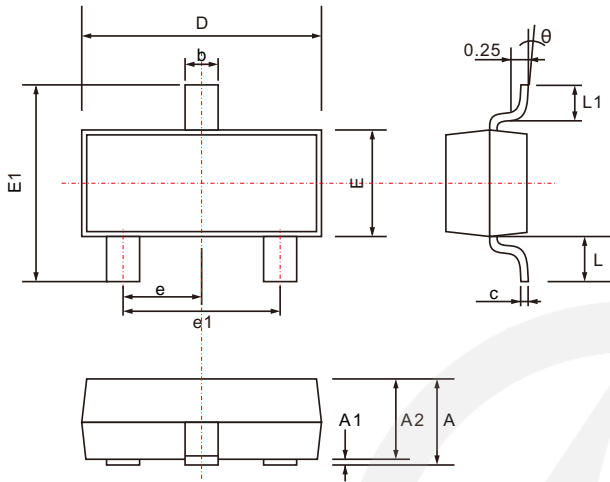
(1).Other voltages available upon request.

(2).Non-repetitive current pulse 8/20 μs exponential decay waveform according to IEC61000-4-5

Characteristic Curves


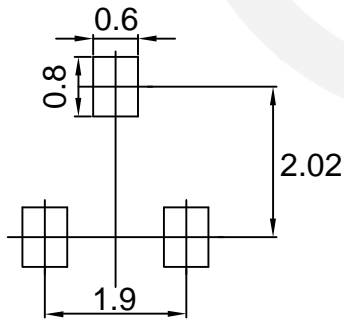
SOT-23 Package Outline

Unit: mm



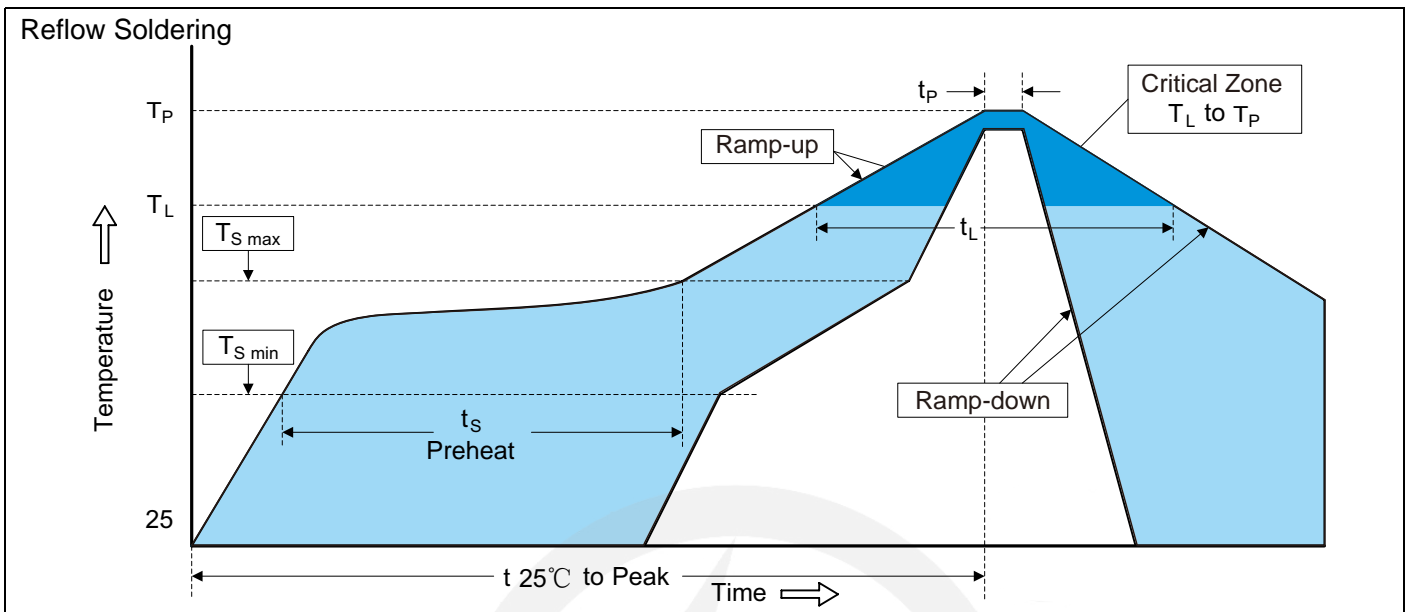
SYMBOL	DIMENSIONS	
	MIN.	MAX.
A	0.900	1.200
A1	0.000	0.100
A2	0.900	1.050
b	0.300	0.500
c	0.080	0.200
D	2.700	3.100
E	1.200	1.400
E1	2.200	3.000
e	0.950 TYP.	
e1	1.750	2.050
L	0.550 TYP.	
L1	0.300	0.500
θ	0°	8°

SOT-23 Suggested Pad Layout

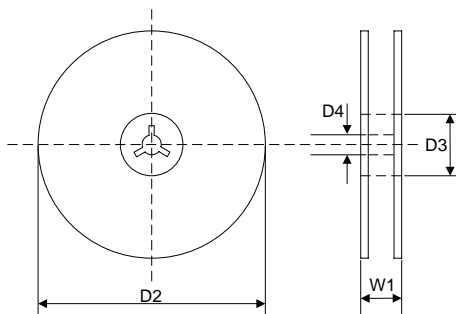


Note:

1. Controlling dimension: in millimeters.
2. General tolerance: $\pm 0.05\text{mm}$
3. The pad layout is for reference purpose only.

Recommended Soldering Conditions

Recommended Conditions

Profile Feature	Pb-Free Assembly
Average ramp-up rate (T_L to T_P)	3°C/second max.
Preheat -Temperature Min ($T_{S\ min}$) -Temperature Max ($T_{S\ max}$) -Time (min to max) (t_s)	150°C 200°C 60-180 seconds
$T_{S\ max}$ to T_L -Ramp-up Rate	3°C/second max.
Time maintained above: -Temperature (T_L) -Time (t_L)	217°C 60-150 seconds
Peak Temperature (T_P)	260°C
Time within 5°C of actual Peak Temperature (t_P)	20-40 seconds
Ramp-down Rate	6°C/second max.
Time 25°C to Peak Temperature	8 minutes max.

7" Reel


D2	$\Phi 178.0 \pm 2.0$
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D3	$\Phi 50.0 \text{ Min.}$
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D4	$\Phi 13.0 \pm 0.5$
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W1	16.0 ± 2.0
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Quantity: 3000PCS